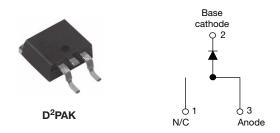
VS-10TQ035SPbF, VS-10TQ045SPbF

Vishay Semiconductors

RoHS

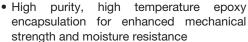
High Performance Schottky Rectifier, 10 A

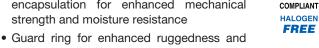


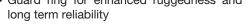
PRODUCT SUMMARY					
Package	D ² PAK				
I _{F(AV)}	10 A				
V _R	35 V, 40 V, 45 V				
V _F at I _F	0.57 V				
I _{RM}	15 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Single die				
E _{AS}	13 mJ				

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- · High frequency operation







- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION

The VS-10TQ...SPbF Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	10	A			
V _{RRM}		35/45	V			
I _{FSM}	t _p = 5 μs sine	1050	A			
V _F	10 A _{pk} , T _J = 125 °C	0.49	V			
T _J	Range	-55 to +175	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-10TQ035SPbF	VS-10TQ045SPbF	UNITS		
Maximum DC reverse voltage	V_{R}	35	45	V		
Maximum working peak reverse voltage	V_{RWM}	33	43	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS	
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 151 °C, r	10	А		
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1050	Α	
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	280		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6.5 mH		13	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero i Frequency limited by T _J maximum	•	2	А	



VS-10TQ035SPbF, VS-10TQ045SPbF

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		
Maximum forward voltage drop See fig. 1		10 A	T 05.00	0.57	V
	V (1)	20 A	T _J = 25 °C	0.67	
	V _{FM} ⁽¹⁾	10 A	T 105 °C	0.49	
		20 A	T _J = 125 °C	0.61	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V - Pated V	2	A
See fig. 2		T _J = 125 °C	V _R = Rated V _R	15	mA
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		900	pF
Typical series inductance	L _S	Measured lead to lead 5	8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation See fig. 4	2.0	
Typical thermal resistance case to heatsink	·		Mounting surface, smooth and greased	0.50	°C/W
Approximate weight				2	g
Approximate weight				0.07	OZ.
minimum				6 (5)	kgf · cm
Mounting torque	maximum			12 (10)	(lbf \cdot in)
Marking device			Case style D ² PAK	10TQ	045S



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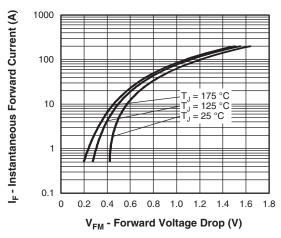


Fig. 1 - Maximum Forward Voltage Drop Characteristics

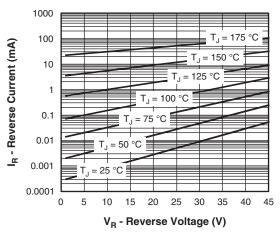


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

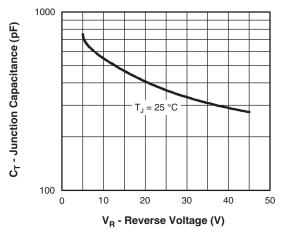


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

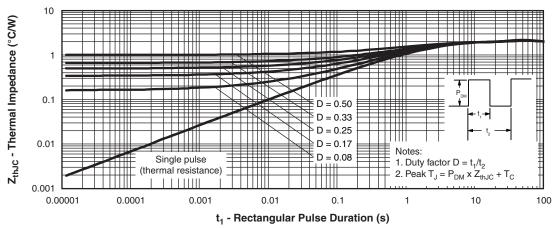


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





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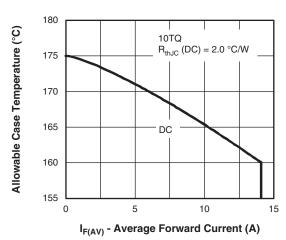


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

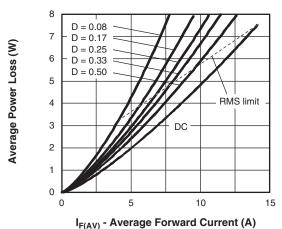


Fig. 6 - Forward Power Loss Characteristics

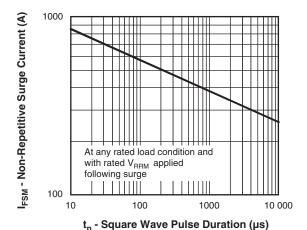


Fig. 7 - Maximum Non-Repetitive Surge Current

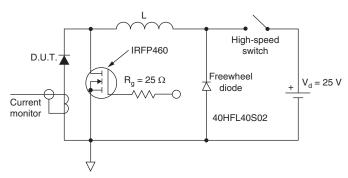


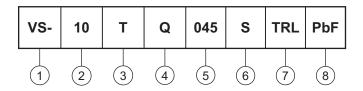
Fig. 8 - Unclamped Inductive Test Circuit

VS-10TQ035SPbF, VS-10TQ045SPbF

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (10 A)

Circuit configuration: T = D²PAK

4 - Schottky "Q" series

035 = 35 V 045 = 45 V

6 - S = D²PAK

7 - • None = tube (50 pieces)

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 - PbF = lead (Pb)-free

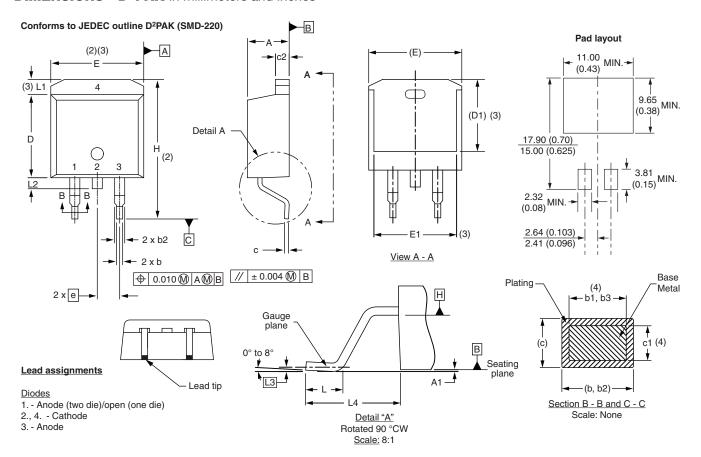
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95014				
Part marking information	www.vishay.com/doc?95008				
Packaging information	www.vishay.com/doc?95032				



Vishay Semiconductors

D²PAK, TO-262

DIMENSIONS - D²PAK in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIMBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

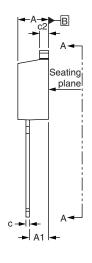
Vishay Semiconductors

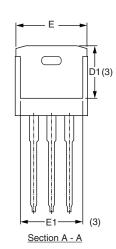
D²PAK, TO-262



DIMENSIONS - TO-262 in millimeters and inches

Modified JEDEC outline TO-262 (Datum A) (2) (3) (3) 1 L2 B B B L (2) 3 x b2 3 x b2 3 x b2





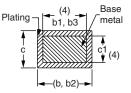
⊕ 0.010 M AM B

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIMETERS		INC	INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- $^{(1)}$ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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